NSN 5961-00-412-4346

Diode Semiconductor Device - Page 1 of 1



view Online at https://aerobasegroup.com/hsh/5961-00-412-4546
Inclosure Material:
Glass
Overall Length:
0.300 inches
Overall Diameter:
0.150 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
5.6 regulator voltage
Current Rating Per Characteristic:
20.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0